

November 2013

FFPF08S60SN

8 A, 600 V, STEALTHTM II Diode

Features

- Stealth Recovery t_{rr} = 25 ns (@ I_F = 8 A)
- Max Forward Voltage, V_F = 3.4 V (@ T_C = 25°C)
- 600 V Reverse Voltage and High Reliability
- · Avalanche Energy Rated
- · RoHS Compliant

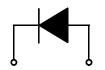
Applications

- · General Purpose
- · SMPS, Power Switching Circuits
- Boost Diode in Continuous Mode Power Factor Corrections

Description

The FFPF08S60SN is a STEALTH™ II diode with soft recovery characteristics. It is silicon nitride passivated ion-implanted epitaxial planar construction. This device is intended for use as freewheeling of boost diode in switching power supplies and other power swithching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.





1. Cathode 2. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage	600	V	
V_{RWM}	Working Peak Reverse Voltage 600			
V _R	DC Blocking Voltage 600			
I _{F(AV)}	Average Rectified Forward Current @ T _C = 60°C	8	Α	
Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave		60	А	
T _J , T _{STG}	Operating and Storage Temperature Range	-65 to +150	°C	

Thermal Characteristics

Symbol	Parameter	Max.	Unit
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	6.8	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFPF08S60SNTU	FFPF08S60SN	TO-220F-2L	Tube	N/A	N/A	50

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter		Min.	Тур.	Max.	Unit
V/ 1	I _F = 8 A	$T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 125^{\rm o}{\rm C}$	-	2.7	3.4	V
V _F 1	I _F = 8 A	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	2.1	-	V
1 1	V _R = 600 V	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	-	100	
I _R 1	V _R = 600 V	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	-	500	μΑ
t _{rr}	$I_F = 1 \text{ A}, \text{ di}_F/\text{dt} = 100 \text{ A/}\mu\text{s}, \text{ V}_R = 30 \text{ V}$	$T_C = 25^{\circ}C$	-	13	-	ns
t _{rr}			-	15	25	ns
I _{rr}	I _E = 8 A, di _E /dt = 200 A/μs, V _R = 390 V	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	2.5	-	Α
S factor	iF = 6 A, dif/dt = 200 A/μs, VR = 390 V	1C = 25 C	-	0.4	-	
Q_{rr}			-	19	-	nC
t _{rr}			-	32	-	ns
Irr	$I_{\rm F} = 8 \text{ A}, di_{\rm F}/dt = 200 \text{A/}\mu\text{s}, V_{\rm R} = 390 \text{V}$	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	3.8	-	Α
S factor	$I_F = 6 \text{ A}, uI_F/uI = 200 \text{ A}/\mu \text{ s}, V_R = 390 \text{ V}$	1 _C = 125 °C	-	0.7	-	
Q_{rr}			-	62	-	nC
W _{AVL}	Avalanche Energy (L = 40 mH)		10	-	-	mJ

Test Circuit and Waveforms

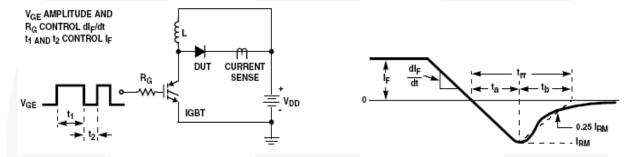


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

L = 40mH R < 0.1Ω $V_{DD} = 50V$ $\mathsf{EAVL} = 1/2\mathsf{LI2} \; [\mathsf{V}_{\mathsf{R}(\mathsf{AVL})}/(\mathsf{V}_{\mathsf{R}(\mathsf{AVL})} - \mathsf{V}_{\mathsf{DD}})]$ Q1 = IGBT (BV_{CES} > DUT V_{R(AVL)}) V_{AVL} CURRENT SENSE V_{DD}

Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

Notes: 1: Pulse: Test Pulse width = 300 μ s, Duty Cycle = 2%

Typical Performance Characteristics

Figure 3. Typical Forward Voltage Drop vs. Forward Current

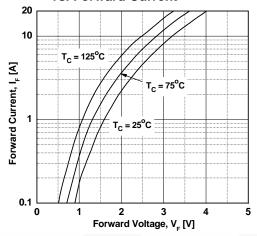


Figure 5. Typical Junction Capacitance

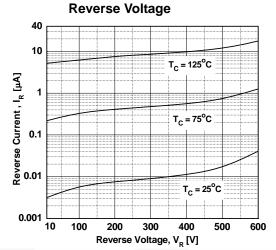


Figure 4. Typical Reverse Current vs.

Figure 6. Typical Reverse Recovery Time vs. di/dt

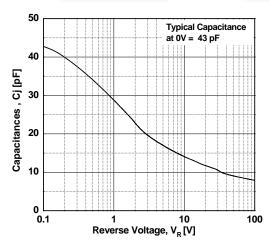


Figure 7. Typical Reverse Recovery Current vs. di/dt

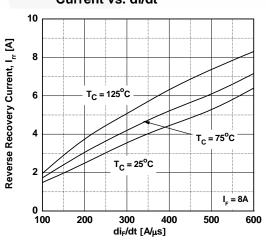
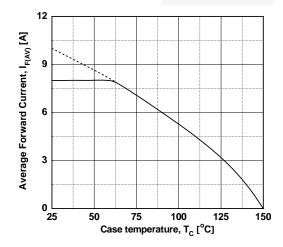


Figure 8. Forward Current Derating Curve



Mechanical Dimensions

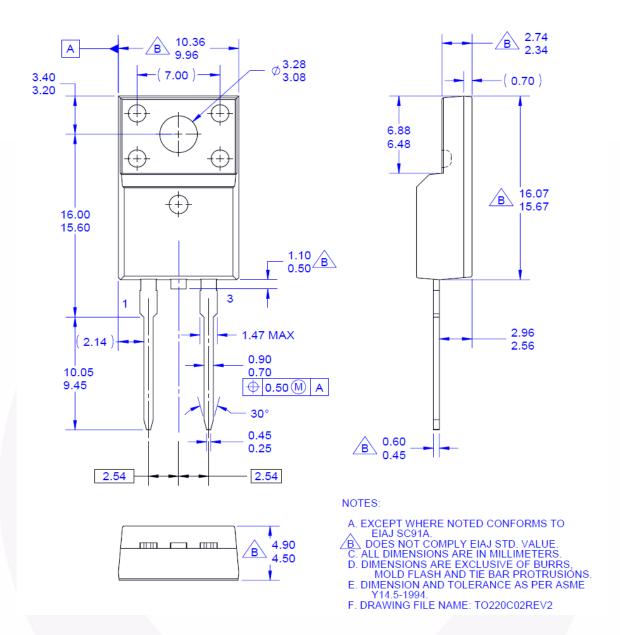


Figure 9. TO-220F 2L - 2LD; TO220; MOLDED; FULL PACK

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